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**Interaction-Driven Insulating States in Bilayer Graphene**

CHUN NING LAU, University of California, Riverside

Bilayer graphene (BLG) at the charge neutrality point (CNP) is unstable to electronic interactions, and expected to host a ground state with spontaneously broken symmetries. Here I will present our transport spectroscopy measurements on singly- and dual-gated suspended BLG devices, which have field effect mobility values up to 250,000 and 100,000 $cm^2/Vs$, respectively. We observe an insulating state at CNP with a gap $\sim$2 meV, which can be closed by elevated temperature, finite doping or a perpendicular electric field of either polarity. For magnetic field B>1T, the gap increases linearly with B. Our work contributes towards understanding the rich interaction-driven physics in BLG.